

#### **DATA SHEET**

# AAT1110: Fast Transient 800 mA Step-Down Converter

### **Applications**

- · Cellular phones
- · Digital cameras
- · Handheld instruments
- · Microprocessor/DSP core/IO power
- · PDAs and handheld computers
- · USB devices

#### **Features**

- Vin range: 2.7 V to 5.5 V
- Vout fixed or adjustable from 0.6 V to Vin
- 27 μA no-load quiescent current
- Output current up to 800 mA
- 1.4 MHz switching frequency
- 120 μs soft start
- · Fast load transient
- Over-temperature protection
- Current limit protection
- 100% duty cycle low-dropout operation
- Shutdown current: <1 μA
- Temperature range: -40 °C to +85 °C
- SC70JW (8-pin, 2.2 mm × 2 mm) package (MSL1, 260 °C per JEDEC-J-STD-020)

#### **Description**

The AAT1110 SwitchReg<sup>TM</sup> is a member of Skyworks' Total Power Management IC (TPMIC<sup>TM</sup>) product family. It is a 1.4 MHz step-down converter with an input voltage range of 2.7 V to 5.5 V and output as low as 0.6 V. Its low supply current, small size, and high switching frequency make the AAT1110 the ideal choice for portable applications.

The AAT1110 is available in either a fixed version with internal feedback or a adjustable version with external feedback resistors. It can deliver up to 800 mA of load current while maintaining a low 27  $\mu\text{A}$  no-load quiescent current. The 1.4 MHz switching frequency minimizes the size of external components while keeping switching losses low. The AAT1110 has excellent load regulation and transient response with a small output inductor and capacitor.

The AAT1110 is designed to maintain high efficiency throughout the operating range and provides fast turn-on time.

The AAT1110 is available in a space-saving 2.0 mm  $\times$  2.2 mm SC70JW-8 package and is rated over the -40 °C to +85 °C temperature range.

A typical application circuit is shown in Figure 1. The pin configuration is shown in Figure 2. Signal pin assignments and functional pin descriptions are provided in Table 1.



1

Skyworks Green<sup>TM</sup> products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green*<sup>TM</sup>, document number SQO4-0074.

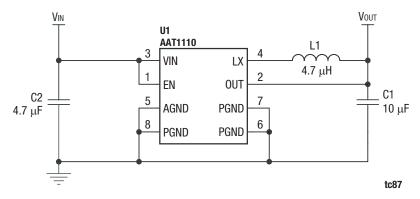


Figure 1. AAT1110 Typical Application Circuit

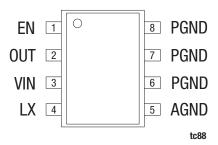


Figure 2. AAT1110 8-Pin SC70JW-8 (Top View)

**Table 1. AAT1110 Pin Descriptions** 

| Pin #   | Name | Description   |
|---------|------|---|
| 1       | EN   | Enable pin.   |
| 2       | OUT  | Feedback input pin. This pin is connected either directly to the converter output or to an external resistive divider for an adjustable output. |
| 3       | VIN  | Input supply voltage for the converter.   |
| 4       | LX   | Switching node. Connect the inductor to this pin. It is internally connected to the drain of both high- and low-side MOSFETs.                   |
| 5       | AGND | Non-power signal ground pin.  |
| 6, 7, 8 | PGND | Main power ground return pin. Connect to the output and input capacitor return.   |

# **Electrical and Mechanical Specifications**

The absolute maximum ratings of the AAT1110 are provided in Table 2, and the electrical specifications are provided in Table 3.

Typical performance characteristics of the AAT1110 are illustrated in Figures 3 through 24.

**Table 2. AAT1110 Absolute Maximum Ratings (Note 1)** 

| Parameter  | Symbol | Minimum | Typical | Maximum   | Units |
|--|--------|---------|---------|-----------|-------|
| Input voltage to GND                                 | Vin    |         | 6.0     |           | ٧     |
| LX to GND  | VLX    | -0.3    |         | Vin + 0.3 | ٧     |
| OUT to GND   | Vouт   | -0.3    |         | Vin + 0.3 | ٧     |
| EN to GND  | VEN    | -0.3    |         | +6.0      | ٧     |
| Operating junction temperature                       | TJ     | -40     |         | +140      | °C    |
| Maximum soldering temperature (at leads, 10 seconds) | TLEAD  |         | 300     |           | °C    |
| Maximum power dissipation (SC70JW-8)                 | PD     |         | 719     |           | mW    |
| Thermal resistance (SC70JW-8) (Note 2)               | θЈА    |         | 160     |           | °C/W  |

Note 1: Exposure to maximum rating conditions for extended periods may reduce device reliability. There is no damage to device with only one parameter set at the limit and all other parameters set at or below their nominal value. Exceeding any of the limits listed may result in permanent damage to the device.

Note 2: Mounted on an FR4 board.

**CAUTION**: Although this device is designed to be as robust as possible, Electrostatic Discharge (ESD) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times.

Table 3. AAT1110 Electrical Specifications (Note 1) (VIN = 3.6 V, TA = -40 °C to 85 °C, Unless Otherwise Noted. Typical Values are at TA = 25 °C)

| Parameter                            | Symbol             | Test Condition                           | Min  | Typical | Max  | Units |  |
|--------------------------------------|--------------------|--|------|---------|------|-------|--|
| Step-Down Converter                  |                    |  |      |         |      |       |  |
| Input voltage                        | VIN                |  | 2.7  |         | 5.5  | V     |  |
|                                      |                    | Vin rising                               |      |         | 2.7  | V     |  |
| UVLO threshold                       | Vuvlo              | Hysteresis                               |      | 100     |      | mV    |  |
|                                      |                    | VIN falling                              | 1.8  |         |      | ٧     |  |
| Output voltage tolerance             | Δ <b>V</b> 0UT     | IOUT = 0 to 800 mA, VIN = 2.7 V to 5.5 V | -3.5 |         | +3.5 | %     |  |
| Output voltage                       | Vout               |  | 0.6  |         | VIN  | ٧     |  |
| Quiescent current                    | IQ                 | No load, 0.6 V adjustable version        |      | 27      | 70   | μА    |  |
| Shutdown current                     | ISHDN              | EN = AGND = PGND                         |      |         | 1.0  | μА    |  |
| P-channel current limit              | ILIM               |  | 800  | 1200    |      | mA    |  |
| High-side switch on resistance       | RDS(ON)H           |  |      | 0.45    |      | Ω     |  |
| Low-side switch on resistance        | RDS(ON)L           |  |      | 0.40    |      | Ω     |  |
| Line regulation                      | $\Delta V$ LINEREG | VIN = 2.7 V to 5.5 V                     |      | 0.1     |      | %/V   |  |
| OUT pin leakage current              | IOUT_LEAK          | 0.6 V output                             |      |         | 0.2  | μА    |  |
| Output impedance                     | Rout               | >0.6 V output                            | 250  |         |      | kΩ    |  |
| Soft-start time                      | tss                | From enable to output regulation         |      | 120     |      | μS    |  |
| Oscillator frequency                 | fosc               | TA = 25 °C                               | 1.0  | 1.4     | 2.0  | MHz   |  |
| Over-temperature shutdown threshold  | TSD                |  |      | 140     |      | °C    |  |
| Over-temperature shutdown hysteresis | THYS               |  |      | 15      |      | °C    |  |
| EN                                   |                    |  |      |         |      |       |  |
| Enable threshold low                 | VEN(L)             |  |      |         | 0.6  | ٧     |  |
| Enable threshold high                | VEN(H)             |  | 1.4  |         |      | ٧     |  |
| Input low current                    | len                | VIN = VOUT = 5.5 V                       | -1.0 |         | 1.0  | μА    |  |

Note 1: Performance is guaranteed only under the conditions listed in this Table.

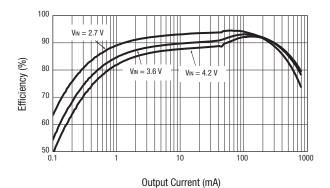


Figure 3. Efficiency vs Load (Vout = 1.8 V, L = 4.7  $\mu$ H)

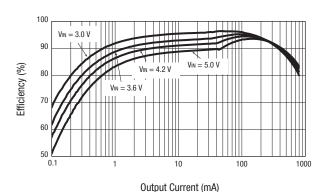


Figure 5. Efficiency vs Load (Vout = 2.5 V, L = 6.8 µH)

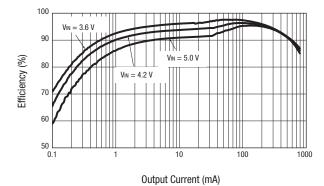


Figure 7. Efficiency vs Load (Vout = 3.3 V, L = 6.8  $\mu$ H)

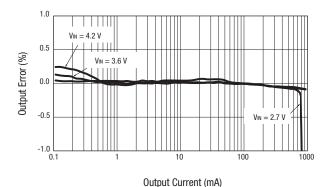


Figure 4. DC Regulation (Vout = 1.8 V)

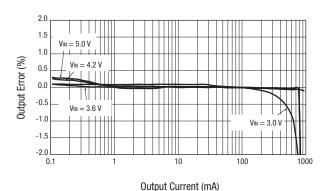


Figure 6. DC Regulation (Vout = 2.5 V)

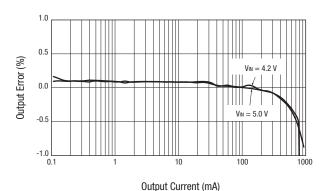
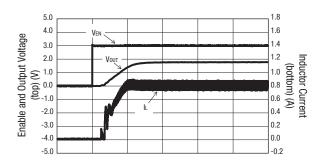


Figure 8. DC Regulation (Vout = 3.3 V)



Time (100 µs/div)

Figure 9. Soft Start (Vin = 3.6 V, Vout = 1.8 V, lout = 800 mA)

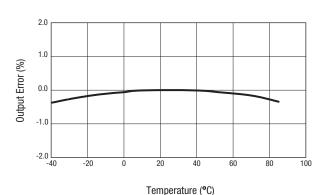


Figure 11. Output Voltage Error vs Temperature (VIN = 3.6 V, VOUT = 1.8 V, IOUT = 400 mA)

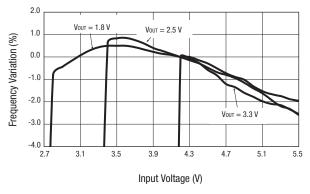


Figure 13. Frequency vs Input Voltage (100T = 800 mA)

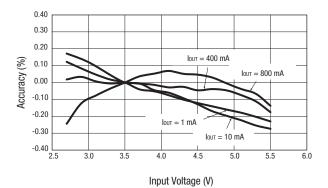


Figure 10. Line Regulation (Vout = 1.8 V)

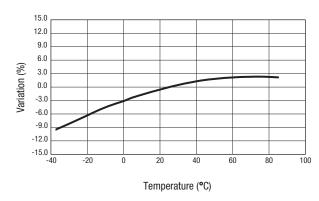


Figure 12. Switching Frequency vs Temperature (VIN = 3.6 V, VOUT = 1.8 V)

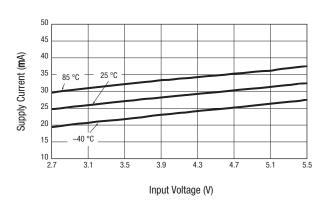
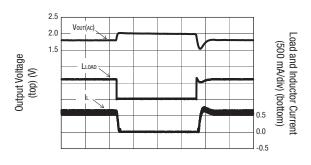
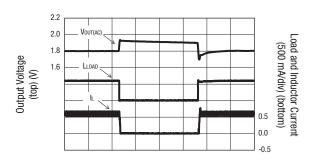


Figure 14. No Load Quiescent Current vs Input Voltage



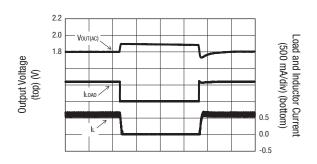
Time (50 µs/div)

Figure 15. Load Transient Response (1 mA to 600 mA, VIN = 3.6 V, VOUT = 1.8 V, C1 = 10  $\mu$ F)



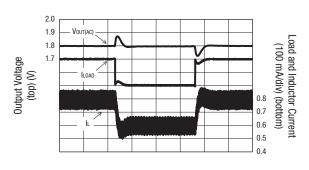
Time (50 µs/div)

Figure 17. Load Transient Response (1 mA to 600 mA, VIN = 3.6 V, VOUT = 1.8 V, C1 = 10  $\mu$ F, CFF = 100 pF)



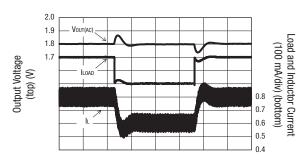
Time (50  $\mu$ s/div)

Figure 19. Load Transient Response (1 mA to 600 mA, VIN = 3.6 V, VOUT = 1.8 V, C1 = 22  $\mu$ F, CFF = 100 pF)



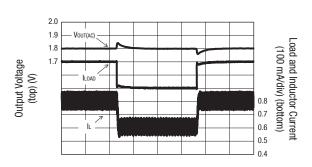
Time (50 µs/div)

Figure 16. Load Transient Response (600 mA to 800 mA, Vin = 3.6 V, Vout = 1.8 V, C1 = 10  $\mu$ F)



Time (50 µs/div)

Figure 18. Load Transient Response (600 mA to 800 mA, Vin = 3.6 V, Vout = 1.8 V, C1 = 22  $\mu\text{F})$ 



Time (50 µs/div)

Figure 20. Load Transient Response (600 mA to 800 mA, VIN = 3.6 V, VOUT = 1.8 V, C1 = 10  $\mu$ F, CFF = 100 pF)



Time (50 µs/div)

Figure 21. Line Response (Vout = 1.8 V @ 800 mA)

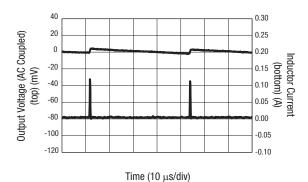


Figure 23. Output Ripple (VIN = 3.6 V, Vout = 1.8 V, lout = 1 mA)

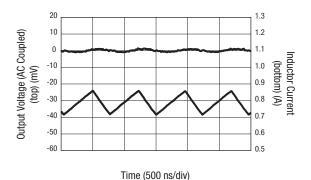


Figure 22. Output Ripple

(VIN = 3.6 V, VOUT = 1.8 V, IOUT = 800 mA)

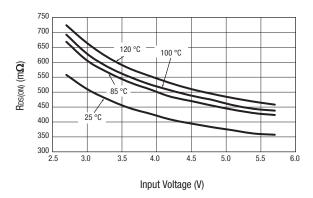


Figure 24. P-Channel RDs(ON) vs Input Voltage (Vout = 1.8 V; CFF = 100 pF)

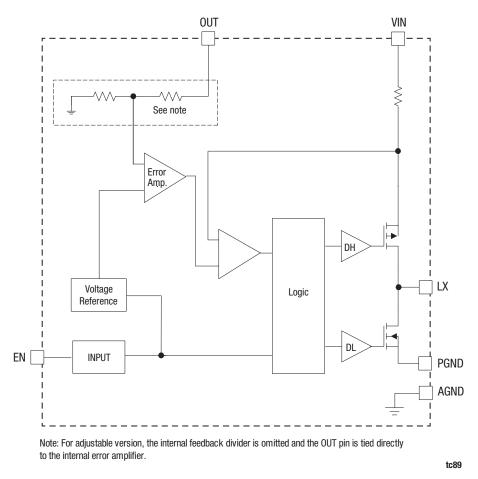


Figure 25. AAT1110 Functional Block Diagram

# **Functional Description**

The AAT1110 is a high performance 800 mA, 1.4 MHz monolithic step-down converter. It has been designed with the goal of minimizing external component size and optimizing efficiency over the complete load range. Apart from the small bypass input capacitor, only a small L-C filter is required at the output. Typically, a 4.7  $\mu\text{H}$  inductor and a 10  $\mu\text{F}$  ceramic capacitor are recommended..

A functional block diagram is shown in Figure 25.

The fixed output version requires only three external power components (CIN, COUT, and L). The adjustable version can be programmed with external feedback to any voltage, ranging from 0.6 V to the input voltage. An additional feed-forward capacitor (C4) can also be added to the external feedback to provide improved transient response (see Figure 26).

At dropout, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the RDSON drop of the P-channel high-side MOSFET.

The input voltage range is 2.7 V to 5.5 V. The converter efficiency has been optimized for all load conditions, ranging from no load to 800 mA.

The internal error amplifier and compensation provides excellent transient response, load, and line regulation. Soft start eliminates any output voltage overshoot when the enable is applied.

#### **Control Loop**

The AAT1110 is a peak current mode step-down converter. The current through the P-channel MOSFET (high side) is sensed for current loop control, as well as short circuit and overload protection. A fixed slope compensation signal is added to the sensed current to maintain stability for duty cycles greater than 50%. The peak current mode loop appears as a voltage-programmed current source in parallel with the output capacitor.

The output of the voltage error amplifier programs the current mode loop for the necessary peak switch current to force a constant output voltage for all load and line conditions. Internal loop compensation terminates the transconductance voltage error amplifier output. For fixed voltage versions, the error amplifier reference voltage is internally set to program the converter output voltage. For the adjustable output, the error amplifier reference is fixed at 0.6 V.

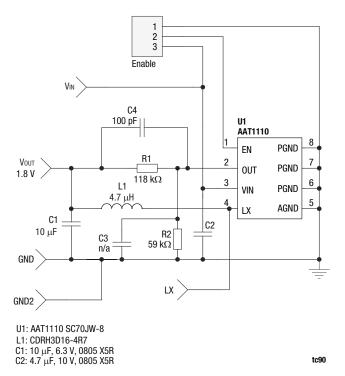


Figure 26. Enhanced Transient Response Schematic

#### **Soft Start/Enable**

Soft start limits the current surge seen at the input and eliminates output voltage overshoot. When pulled low, the enable input forces the AAT1110 into a low power, non-switching state. The total input current during shutdown is less than 1  $\mu$ A.

#### **Current Limit and Over-Temperature Protection**

For overload conditions, the peak input current is limited. To minimize power dissipation under current limit and short-circuit conditions, switching is terminated after entering current limit for a series of pulses. Switching is terminated for seven consecutive clock cycles after a current limit has been sensed for a series of four consecutive clock cycles.

Thermal protection completely disables switching when internal dissipation becomes excessive. The junction over-temperature threshold is 140 °C with 15 °C of hysteresis. Once an over-temperature or over-current fault conditions is removed, the output voltage automatically recovers.

#### **Under-Voltage Lockout**

Internal bias of all circuits is controlled via the VIN input. Undervoltage lockout (UVLO) guarantees sufficient VIN bias and proper operation of all internal circuitry prior to activation.

#### **Applications Information**

#### **Inductor Selection**

The step-down converter uses peak current mode control with slope compensation to maintain stability for duty cycles greater than 50%. The output inductor value must be selected so the inductor current down slope meets the internal slope compensation requirements. The internal slope compensation for the adjustable and low-voltage fixed versions of the AAT1110 is 0.24 A/ $\mu s$ . This equates to a slope compensation that is 75% of the inductor current down slope for a 1.5 V output and 4.7  $\mu H$  inductor.

$$m = \frac{0.75 \times V_{OUT}}{L} = \frac{0.75 \times 1.5V}{4.7 \,\mu\text{H}} = 0.24 \,\frac{A}{\mu\text{s}}$$

This is the internal slope compensation for the adjustable (0.6 V) version or low-voltage fixed versions. When externally programming the 0.6 V version to 2.5 V, the calculated inductance is 7.5  $\mu$ H.

$$L = \frac{0.75 \times V_{OUT}}{m} = \frac{0.75 \times V_{OUT}}{0.24 \frac{A}{\mu s}} \approx 3 \frac{\mu s}{A} \times V_{OUT}$$
$$= 3 \frac{\mu s}{A} \times 2.5V = 7.5 \mu H$$

In this case, a standard 6.8 µH value is selected.

For high-voltage fixed versions ( $\geq 2.5$  V), m = 0.48 A/ $\mu$ s.

Manufacturer's specifications list both the inductor DC current rating, which is a thermal limitation, and the peak current rating, which is determined by the saturation characteristics. The inductor should not show any appreciable saturation under normal load conditions. Some inductors may meet the peak and average current ratings yet result in excessive losses due to a high DCR. Always consider the losses associated with the DCR and its effect on the total converter efficiency when selecting an inductor.

#### **Input Capacitor**

Select a 4.7  $\mu$ F to 22  $\mu$ F X7R or X5R ceramic capacitor for the input. To estimate the required input capacitor size, determine the acceptable input ripple level (VPP) and solve for C. The calculated value varies with input voltage and is a maximum when Vin is double the output voltage.

$$C_{\mathit{IN}} = \frac{\frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}} \times \left(I - \frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}}\right)}{\left(\frac{V_{\mathit{PP}}}{I_{\mathit{OUT}}} - ESR\right) \times f_{\mathit{S}}}$$
 
$$\frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}} \times \left(I - \frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}}\right) = \frac{1}{4} \quad \textit{for} \quad V_{\mathit{IN}} = 2 \times V_{\mathit{OUT}}$$

$$C_{IN(MIN)} = \frac{1}{\left(\frac{V_{PP}}{I_{OUT}} - ESR\right) \times 4 \times f_{S}}$$

Where, fs is the switching frequency.

Always examine the ceramic capacitor DC voltage coefficient characteristics when selecting the proper value. For example, the capacitance of a 10  $\mu$ F, 6.3 V, X5R ceramic capacitor with 5.0 V DC applied is actually about 6  $\mu$ F.

The maximum input capacitor RMS current is:

$$I_{\mathit{RMS}} = I_{\mathit{OUT}} \times \sqrt{\frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}}} \times \left(1 - \frac{V_{\mathit{OUT}}}{V_{\mathit{IN}}}\right)$$

The input capacitor RMS ripple current varies with the input and output voltage and always is less than or equal to half of the total DC load current.

$$\sqrt{\frac{V_{OUT}}{V_{IN}} \times \left(I - \frac{V_{OUT}}{V_{IN}}\right)} = \sqrt{D \times \left(I - D\right)} = \sqrt{0.5^2} = \frac{1}{2}$$

for  $Vin = 2 \times Vout$ 

$$I_{RMS\ (MAX)} = \frac{I_{OUT}}{2}$$

The term  $\frac{V_{our}}{V_{\scriptscriptstyle IN}} \times \left(I - \frac{V_{our}}{V_{\scriptscriptstyle IN}}\right)$  appears in both the input voltage

ripple and input capacitor RMS current equations and is a maximum when Vout is twice Vin. This is why the input voltage ripple and the input capacitor RMS current ripple are a maximum at 50% duty cycle.

The input capacitor provides a low impedance loop for the edges of pulsed current drawn by the AAT1110. Low ESR/ESL X7R and X5R ceramic capacitors are ideal for this function. To minimize stray inductance, the capacitor should be placed as closely as possible to the IC. This keeps the high frequency content of the input current localized, minimizing EMI and input voltage ripple.

The proper placement of the input capacitor (C2) can be seen in the evaluation board layout in Figure 28.

A laboratory test setup typically consists of two long wires running from the bench power supply to the evaluation board input voltage pins. The inductance of these wires, along with the low-ESR ceramic input capacitor, can create a high-Q network that may affect converter performance. This problem often becomes apparent in the form of excessive ringing in the output voltage during load transients. Errors in the loop phase and gain measurements can also result.

Because the inductance of a short PCB trace feeding the input voltage is significantly lower than the power leads from the bench power supply, most applications do not exhibit this problem.

In applications where the input power source lead inductance cannot be reduced to a level that does not affect the converter performance, a high ESR tantalum or aluminum electrolytic should be placed in parallel with the low ESR, ESL bypass ceramic. This dampens the high-Q network and stabilizes the system.

#### **Output Capacitor**

The output capacitor limits the output ripple and provides holdup during large load transitions. A 4.7  $\mu\text{F}$  to 10  $\mu\text{F}$  X5R or X7R ceramic capacitor typically provides sufficient bulk capacitance to stabilize the output during large load transitions and has the ESR and ESL characteristics necessary for low output ripple.

The output voltage droop due to a load transient (\( \Delta LOAD \)) is dominated by the capacitance of the ceramic output capacitor. During a step increase in load current, the ceramic output capacitor alone supplies the load current until the loop responds. Within two or three switching cycles, the loop responds and the inductor current increases to match the load current demand. The relationship of the output voltage droop during the three switching cycles to the output capacitance can be estimated by:

$$C_{OUT} = \frac{3 \times \Delta I_{LOAD}}{V_{DROOP} \times f_S}$$

Once the average inductor current increases to the DC load level, the output voltage recovers. The above equation establishes a limit on the minimum value for the output capacitor with respect to load transients.

The internal voltage loop compensation also limits the minimum output capacitor value to 4.7  $\mu$ F. This is due to its effect on the loop crossover frequency (bandwidth), phase margin, and gain margin. Increased output capacitance reduces the crossover frequency with greater phase margin.

The maximum output capacitor RMS ripple current is given by:

$$I_{RMS~(MAX)} = \frac{1}{2\sqrt{3}} \times \frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{L \times f_s \times V_{IN(MAX)}}$$

Dissipation due to the RMS current in the ceramic output capacitor ESR is typically minimal, resulting in less than a few degrees rise in hot-spot temperature.

### **Adjustable Output Resistor Selection**

For applications requiring an adjustable output voltage, the 0.6 V version can be externally programmed. Resistors R1 and R2 of Figure 28 program the output to regulate at a voltage higher than 0.6 V. To limit the bias current required for the external feedback resistor string while maintaining good noise immunity, the minimum suggested value for R2 is  $59~k\Omega$ . Although a larger value can further reduce quiescent current, it also increases the impedance of the feedback node, making it more sensitive to external noise and interference. Table 4 summarizes the resistor values for various output voltages with R2 set to either  $59~k\Omega$  for good noise immunity or  $221~k\Omega$  for reduced no-load input current.

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2 = \left(\frac{1.5V}{0.6V} - 1\right) \times 59k\Omega = 88.5k\Omega$$

The adjustable version of the AAT1110, combined with an external feed-forward capacitor (C4 in Figure 26), delivers enhanced transient response for extreme pulsed load applications. Addition of the feed-forward capacitor typically requires a larger output capacitor C1 for stability.

Table 4. Adjustable Resistor Values for Use with 0.6 V Step-Down Converter

| <b>V</b> оит <b>(V)</b> | R1 (kΩ)<br>(R2 = 59 kΩ) | R1 ( $k\Omega$ )<br>(R2 = 221 $k\Omega$ ) |
|-------------------------|-------------------------|---|
| 0.8                     | 19.6                    | 75  |
| 0.9                     | 29.4                    | 113                                       |
| 1.0                     | 39.2                    | 150                                       |
| 1.1                     | 49.9                    | 187                                       |
| 1.2                     | 59.0                    | 221                                       |
| 1.3                     | 68.1                    | 261                                       |
| 1.4                     | 78.7                    | 301                                       |
| 1.5                     | 88.7                    | 332                                       |
| 1.8                     | 118                     | 442                                       |
| 1.85                    | 124                     | 464                                       |
| 2.0                     | 137                     | 523                                       |
| 2.5                     | 187                     | 715                                       |
| 3.3                     | 267                     | 1000                                      |

#### **Thermal Calculations**

There are three types of losses associated with the AAT1110 step-down converter: switching losses, conduction losses, and quiescent current losses. Conduction losses are associated with the RDS(0N) characteristics of the power output switching devices. Switching losses are dominated by the gate charge of the power output switching devices. At full load, assuming continuous conduction mode (CCM), a simplified form of the losses is given by:

$$\begin{split} P_{\scriptscriptstyle TOTAL} &= \frac{I_{\scriptscriptstyle OUT}^2 \times \left(R_{\scriptscriptstyle DS(\scriptscriptstyle ON\,)H} \times V_{\scriptscriptstyle OUT} + R_{\scriptscriptstyle DS(\scriptscriptstyle ON\,)L} \times \left[V_{\scriptscriptstyle IN} - V_{\scriptscriptstyle OUT}\right]\right)}{V_{\scriptscriptstyle IN}} \\ &+ \left(t_{\scriptscriptstyle SW} \times f_{\scriptscriptstyle S} \times I_{\scriptscriptstyle OUT} + I_{\scriptscriptstyle Q}\right) \times V_{\scriptscriptstyle IN} \end{split}$$

lo is the step-down converter quiescent current. The term tsw is used to estimate the full load step-down converter switching losses.

For the condition where the step-down converter is in dropout at 100% duty cycle, the total device dissipation reduces to:

$$P_{TOTAL} = I_{OUT}^2 \times R_{DS(ON)H} + I_O \times V_{IN}$$

Since RDS(ON), quiescent current, and switching losses all vary with input voltage, the total losses should be investigated over the complete input voltage range.

Given the total losses, the maximum junction temperature can be derived from the  $\theta$ JA for the SC70JW-8 package which is 160 °C/W.

$$T_{I(MAX)} = P_{TOTAL} \times \theta_{IA} + T_A$$

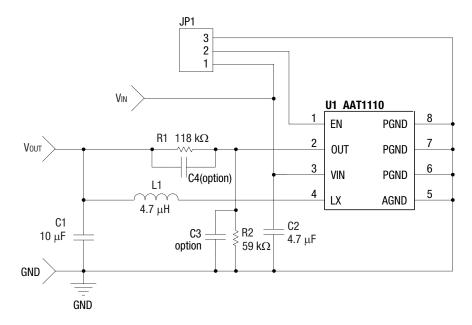
#### Lavout

The following guidelines should be used to help ensure a proper layout.

- The input capacitor (C2) should connect as closely as possible to VIN (Pin 3) and PGND (Pins 6-8).
- C1 and L1 should be connected as closely as possible. The connection of L1 to the LX pin should be as short as possible.
- The feedback trace or OUT pin (Pin 2) should be separate from any power trace and connect as closely as possible to the load point. Sensing along a high-current load trace degrades DC load regulation. If external feedback resistors are used, they should be placed as closely as possible to the OUT pin (Pin 2) to minimize the length of the high impedance feedback trace.
- The resistance of the trace from the load return to the PGND (Pins 6-8) should be kept to a minimum. This helps minimize any error in DC regulation due to differences in the potential of the internal signal ground and the power ground.

#### **Evaluation Board Description**

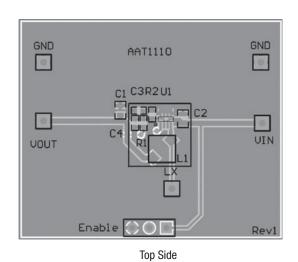
The AAT1110 Evaluation Board schematic diagram is provided in Figure 27. The PCB layer details are shown in Figure 28. Table 5 lists the evaluation board component values. Tables 6 and 7 give the typical surface mount inductors and surface mount capacitors.

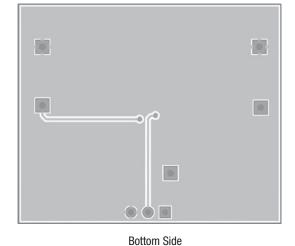


U1: AAT1110 SC70JW-8 L1: CDRH3D16-4R7 C1: 10 μF, 6.3 V, 0805 X5R C2: 4.7 μF, 10 V, 0805 X5R

tc91

Figure 27. AAT1110 Adjustable Evaluation Board Schematic





tc92

Figure 28. AAT1110 Evaluation Board Layer Details

**Table 5. Evaluation Board Component Values** 

| Adjustable Version (0.6 V device) |  |  |         |  |  |  |
|-----------------------------------|--|--|---------|--|--|--|
| <b>V</b> оит ( <b>V</b> )         | R1 ( $k\Omega$ )<br>(R2 = 59 $k\Omega$ ) | R1 ( $k\Omega$ )<br>(R2 = 221 $k\Omega$ ) (Note 1) | L1 (μH) |  |  |  |
| 0.8                               | 19.6                                     | 75.0   | 2.2     |  |  |  |
| 0.9                               | 29.4                                     | 113  | 2.2     |  |  |  |
| 1.0                               | 39.2                                     | 150  | 2.2     |  |  |  |
| 1.1                               | 49.9                                     | 187  | 2.2     |  |  |  |
| 1.2                               | 59.0                                     | 221  | 2.2     |  |  |  |
| 1.3                               | 68.1                                     | 261  | 2.2     |  |  |  |
| 1.4                               | 78.7                                     | 301  | 4.7     |  |  |  |
| 1.5                               | 88.7                                     | 332  | 4.7     |  |  |  |
| 1.8                               | 118                                      | 442  | 4.7     |  |  |  |
| 1.85                              | 124                                      | 464  | 4.7     |  |  |  |
| 2.0                               | 137                                      | 523  | 6.8     |  |  |  |
| 2.5                               | 187                                      | 715  | 6.8     |  |  |  |
| 3.3                               | 267                                      | 1000   | 6.8     |  |  |  |
| Fixed Version                     |  |  |         |  |  |  |
| Vout (V)                          | (R1, R2 Not Used)                        |  |         |  |  |  |
| 0.6-3.3V                          | (K1, K2)                                 | 4.7  |         |  |  |  |

Note 1: For reduced quiescent current, R2 = 221 k $\Omega$ .

### **Table 6. Typical Surface Mount Inductors**

| Manufacturer | Part Number/Type | Inductance<br>(µH) | Max. DC Current<br>(A) | DCR<br>(mΩ) | Size (mm)<br>L×W×H |
|--------------|------------------|--------------------|------------------------|-------------|--------------------|
| ТОКО         | 1276AS-H-2R2N    | 2.2                | 1.60                   | 98          | 3.2×2.5×1.0        |
| ТОКО         | 1239AS-H-4R7M    | 4.7                | 1.30                   | 200         | 2.5×2.0×1.2        |
| Т0К0         | 1277AS-H-6R8N    | 6.8                | 1.20                   | 230         | 3.2×2.5×1.2        |
| Murata       | LQM2HPN2R2MMR    | 2.2                | 1.38                   | 68          | 2.5×2.0×1.1        |
| Murata       | LQH32PN4R7NNC    | 4.7                | 1.20                   | 155         | 3.1×3.1×1.5        |
| Coilcraft    | LPS3015-222MLB   | 2.2                | 2.0                    | 110         | 3.1×3.1×1.5        |

#### **Table 7. Surface Mount Capacitors**

| Manufacturer | Part Number       | Value (μF) | Voltage (V) | Temperature Coefficient | Case |
|--------------|-------------------|------------|-------------|-------------------------|------|
| Murata       | GRM219R61A475KE19 | 4.7        | 10          | X5R                     | 0805 |
| Murata       | GRM21BR60J106KE19 | 10         | 6.3         | X5R                     | 0805 |
| Murata       | GRM21BR60J226ME39 | 22         | 6.3         | X5R                     | 0603 |

# **Package Information**

Package dimensions and tape & reel dimensions are shown in Figures 29 and 30, respectively.

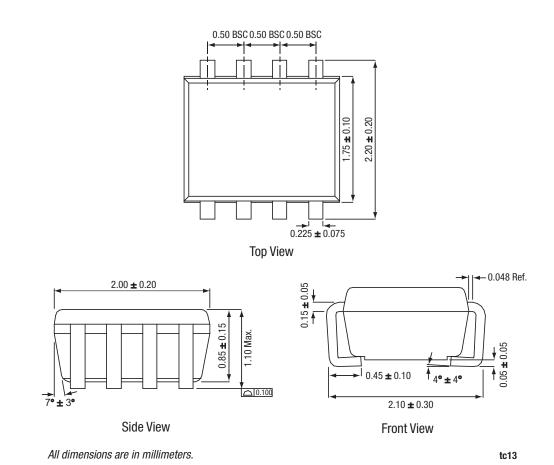


Figure 29. AAT1110 8-pin SC70JW Package Dimensions

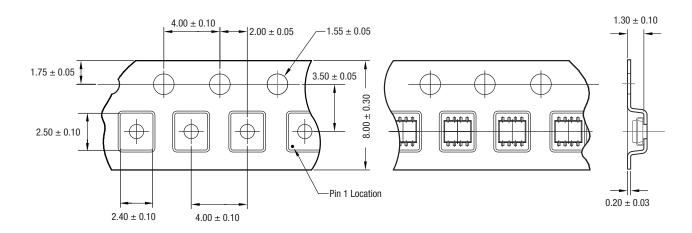


Figure 30. AAT1110 Carrier Tape Dimensions

tc38

All dimensions are in millimeters.

#### **Ordering Information**

| Model Name                    | Output Voltage (Note 1) | Package  | Marking (Note 2) | Manufacturing Part Number (Note 3) |
|-------------------------------|-------------------------|----------|------------------|------------------------------------|
| AAT1110 Fast Transient 800 mA | 3.3 V                   | SC70JW-8 | TSXYY            | AAT1110IJS-3.3-T1                  |
| Step-Down Converter           | $Adj. \geq 0.6 \ V$     | SC70JW-8 | SRXYY            | AAT1110IJS-0.6-T1                  |

Note 1: Contact Sales for other voltage options.

Note 2: XYY = assembly and date code.

Note 3: Sample stock is generally held on part numbers listed in BOLD.

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